New Jersey Semi-Conductor Products, Inc.

20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081

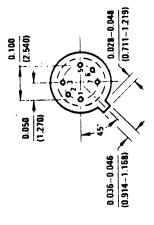
N-Channel JFETs

TELEPHONE: (201) 376-2922 (212) 227-6005 FAX: (201) 376-8960

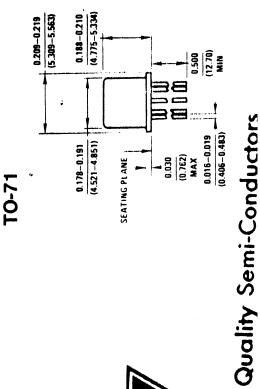
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-	\vdash		Operatin	g Condit	tions fo	Operating Conditions for these Characteristics	haracte	ristics																	
Type Case No. Style		Op. Char. Voc Ip	Op. (V _{GS1-2}) Drift Char. V _{OS} (μV/ ⁷ C G I _D (mV) ΔV _{GS}	DHR (µV/°C) ∆V _{GS}) ^I G (PA) Max I	Drift lc Gts Goas CMRF (μV/°C) PA) μmhos (μmho) (dB) ΔVGS Max Min Max Max Min	G _{oes} CMRR (µmho) (dB) Max Min	سم ا	V _{gs} (V) Min Max		ax Mii	loss (mA) in Max	VP IDSS Gts (V) (mA) (mmho) Min Max Min Max	Gts G _{oss} (mmho) (µmho) Min Max Max	lgs (pA @ Max	3 ⁸ °	Ciss C (pF) (F Max M	C _{ras} BV (pF) (V) Max Min	(nV1 Max	en /Hz@f (Hz)	l _{DSS} Match %	G _{fs} Match	Goect-2 lg1-lg2 Process (µmho) 125°C No.	G1 ⁻¹ G2 125°C (nA)	rocess No.
215 TO 21					100	100 500 1000	-	100	02 38	0.7	4 40.5	5 7.5	-	₽ ₽	250	e	25	5.0 40	8	10	5	e	0.1	<u>0</u>	8
2N5516 TO-71 20	212-0		n n	, QI	001	100 500 1000	• •		0.2 3.8		0	~	4	10	250	8		5.0 40		10	ŝ	e	0.1	10	95
17-01 71-54NS	2 12-0		0	20	100	100 500 1000	. .		0.2 3.8		<u></u>	5 7.5	1	10	250	8	5 2	5.0 40	8	10	5	5	0.1	0	95
2N551A TO-71		20 200	15	40	100	100 500 1000	-		0.2 3.8		0	\$ 7.5	4	10	250	8		50 40		10	5	5	0.1	10	95
2N5519 TO-71 20	0-71 2		15	80	100	100 500 1000	-			0.7	र्भ	5 75	1	9	250	ĝ		5.0 40		10	10	10	0.1	10	95
2NE520 TO-71 20	12.0	000	5	۰ د	100	100 500 1000	-	100	02 38	0.7	4	5 7.5	-	0	250	30	25	5.0 40	15	10	5	ю	0.1	10	95
2N5521 TO-71			s un	, C	100	100 500 1000	-		0.2 3.8		4 0.5	5 75	u t	9	250	30		5.0 40	15	10	5	ო	0.1	10	95
2N5522 TO-71			, C	2 2	001	100 500 1000	-		0.2 3.8		4 0.5	5 75	·	<u>چ</u>	250	8	52	50 40		10	5	ŝ	0.1	10	95
2N5523 TO-71			15	4	100	100 500 1000			0.2 3.8		4 0.5	5 7.5		0	250	30	52	5.0 40		10	5	5	0.1	0	95
2N5524 TO-71 20	0-71		15	80	100	100 500 1000	-				4 0.5	5 7.5	ж 	<u>ج</u> ر 	250	g	52.	5.0 40	15	10	10	10	0.1	0	95
2N6483 TO-71 20	1.0		د. ا	5	100	100 500 1500	-	100	0.2 38	0.7	4 0.5	5 7.5		2	200	g		3.5 50	10	10	5	Э	0.1	10	96
2N6484 TO-71 20		002 02	10	0	100	100 500 1500	-	100	0.2 3.8		4 0.5	5 7.5		10	200	8		3.5 50	10	10	5	e	0.1	0	95
2N6485 TO-71 20	12.0	200	·	25	100	100 500 1500		8	0.2 3.8		4 0.5	5 7.5	-	10	200	8	8	3.5 50	10	10	5	e	0.1	0	95
	-																								



FET (12)	S1	5	5	S2	02	62
Pin	1	2	e	S	9	~





U.S.A.